

138-174 MHz, 25/1 WATT POWER AMPLIFIER

I9D424583GI "M" SERIES MOBILE

I9D424583G5 "E" SERIES MOBILE

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DESCRIPTION

The MASTR[®] II modularized 25 Watt PA assembly for MARINE HI-LO Power Applications contains a 25 Watt PA module, directional coupler, power control circuitry and low pass filter. Two transistors are used to provide 25 Watts or 1 Watt of RF output power. The output power is adjustable from 5 Watts to 25 Watts or 0.5 Watt to 5 Watts and is held constant for normal variations in temperature and voltage.

Supply voltage for the PA is connected through power leads to feedthrough capacitors C297 and C298 on the bottom of the PA assembly. C297, C298, C299, L12, L13 and L201 prevent RF from getting on the power leads. Diode CR295 will cause the main fuse in the fuse assembly to blow if the polarity of the power leads is reversed, providing reverse voltage protection for the radio.

The PA assembly is isolated from vehicle ground to permit operation in positive or negative ground vehicles.

NOTE

In positive ground vehicles, A- is "hot" with respect to vehicle ground. Shorting the transmitter PA printed wiring board ground pattern to the radio case may cause one of the in-line fuses to blow.

Centralized metering jack J205 is provided for use with GE Test Set Model 4EX3A11 or Test Kit 4EX8K12. The Test Set meters Ampl-1 drive (exciter output), power control voltage, and PA current.

CIRCUIT ANALYSIS

25 WATT PA MODULE A202

The exciter output is coupled through and RF cable to PA input jack J201. The RF is coupled through a matching network to the base of Class C amplifier Q1. The network matches the 50-ohm input to the base of Q1 and consists of A202-T1, C5, and C39.

R3, C3, R13 and L1 are stabilizing networks in the base circuit of Q1.

Part of the RF input is rectified by CR1 and is applied to voltage divider R1 and R2. The voltage is divided to activate the Power Control circuits and for metering the Ampl-1 drive at J205.

Collector voltage to Q1 is controlled by the Power Control circuit, and is applied to Q1 through collector stabilizing network L4 and R4 and collector feed network L3 and C6. The collector voltage is metered through R7 at J205-3 (Pos. C).

The output of Q1 is coupled to the base of Class C amplifier Q2 through a matching network consisting of C10, C12, C13, C14, L5 and L6. Collector voltage to Q2 is applied through collector stabilizing network L11 and R6 and collector feed network L8 and C15.

The output of the PA is taken from the collector of Q2, matched to 50 ohms, and applied to the Low Pass Filter (FL201) through microstrips A202-W2, A203-W1, FL201-W1, and connector straps W30 and W31.

The collector impedance matching network for A202-Q2 (L9, L10, C19, C20 and C21) matches the output of Q2 to 50 ohm microstrip A202-W2. C22 is a DC blocking capacitor.

WARNING

The RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic, or toher encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

POWER CONTROL CIRCUIT

The power control circuit consists of power control IC A202-U1, thermistor RT201, High Power adjust potentiometer A202-R8,

Low Power adjust potentiometer R2101, pass transistor Q215 and the directional coupler. The power control IC senses the presence of drive power from the exciter, the heatsink temperature, power output level, reflected power, and input voltage to provide automatic power leveling across the frequency band.

When the transmitter is keyed, rectified RF from A202-CR1 is applied to pin 10 of U1, turning it on. U1 supplies a reference voltage through pin 4 to power adjust potentiometer A202-R8. The voltage appearing at the arm of R8 is determined not only by adjustment of R8 but also by the meter R2101 when the MARINE HI-LOW switch on the control unit is on the LO position. This voltage is applied to pin 2 of U1, causing U1 to adjust the base voltage of Q215.

The conduction of Q215 sets the collector voltage for driver A202-Q1 thereby controlling the RF drive to the PA. The RF output power varies in direct proportion to the RF drive applied to the PA and can be adjusted from approximately 5 to 25 Watts in the HI Power mode of operation on from 0.5 to 5 Watts in the LO Power mode.

Once the power is set to the desired level, U1 compares the reference voltage appearing at the arm of power adjust control R8 to the actual output power flowing through the directional coupler and adjusts the collector voltage of A202-Q1 accordingly. A203-CR1 rectifies the sensed forward power from the directional coupler and A203-R1 sets the forward power reference voltage applied to pin 1 of U1.

Reflected power is sensed by the directional coupler and rectified by A203-CR2. When the reflected power exceeds a preset level established by A203-R2, a DC voltage proportional to the reflected power is applied to pin 3 of U1. U1 lowers the base voltage of Q215, which in turn lowers the collector voltage of A202-Q1, thereby reducing transmitter output power.

Temperature protection is provided by U1 and thermistor RT201. RT201 is mounted on the heatsink assembly. Under normal operating conditions, the temperature sensing circuit is inactive. When the heatsink temperature reaches approximately 100°C, the resistance of RT201 decreases, decreasing the base voltage of Q215. This in turn reduces the collector voltage applied to A202-Q1, reducing the transmitter output until, at approximately 125°C, the output power is almost zero. As the temperature of the heatsink decreases the output power increases until full power returns at approximately 100°C.

Overvoltage protection for the RF transistors is also provided by U1. Should the supply voltage exceed approximately 18 Volts, U1 will switch off the collector voltage to A202-Q1, turning it off and thereby removing drive to the PA. The IC will hold A202-Q1 off until the supply voltage is reduced to a safe level.

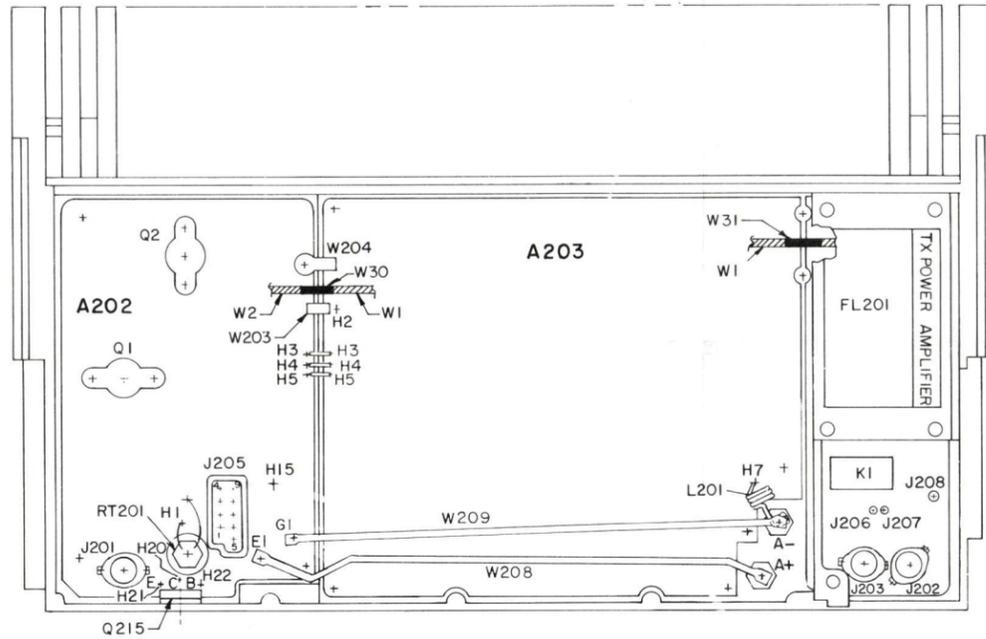
CAUTION

U1 may be damaged if output terminals 12 or 14 are shorted to ground. Use extreme caution when servicing the power control circuit.

MOBILE RADIO DEPARTMENT
GENERAL ELECTRIC COMPANY • LYNCHBURG, VIRGINIA 24502

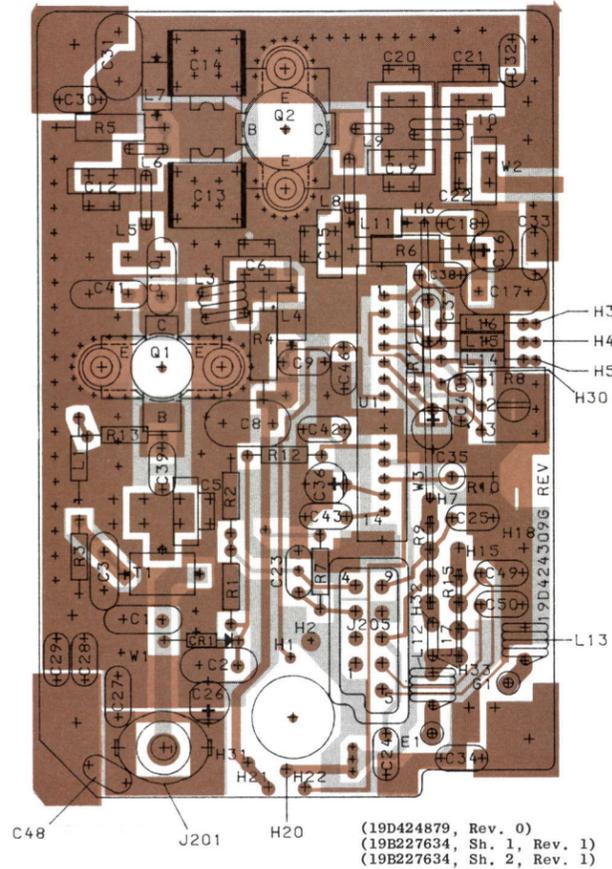
GENERAL  **ELECTRIC**

TOP VIEW

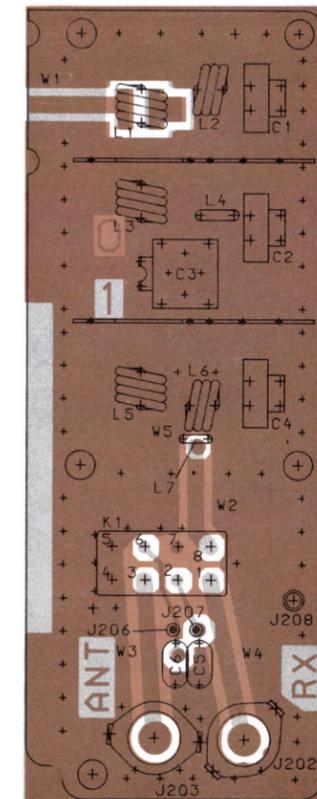


A203 COUPLER BOARD

A202 POWER AMPLIFIER

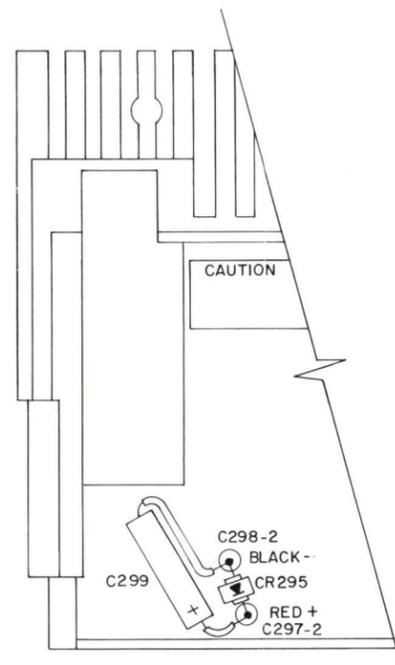


LOW PASS FILTER

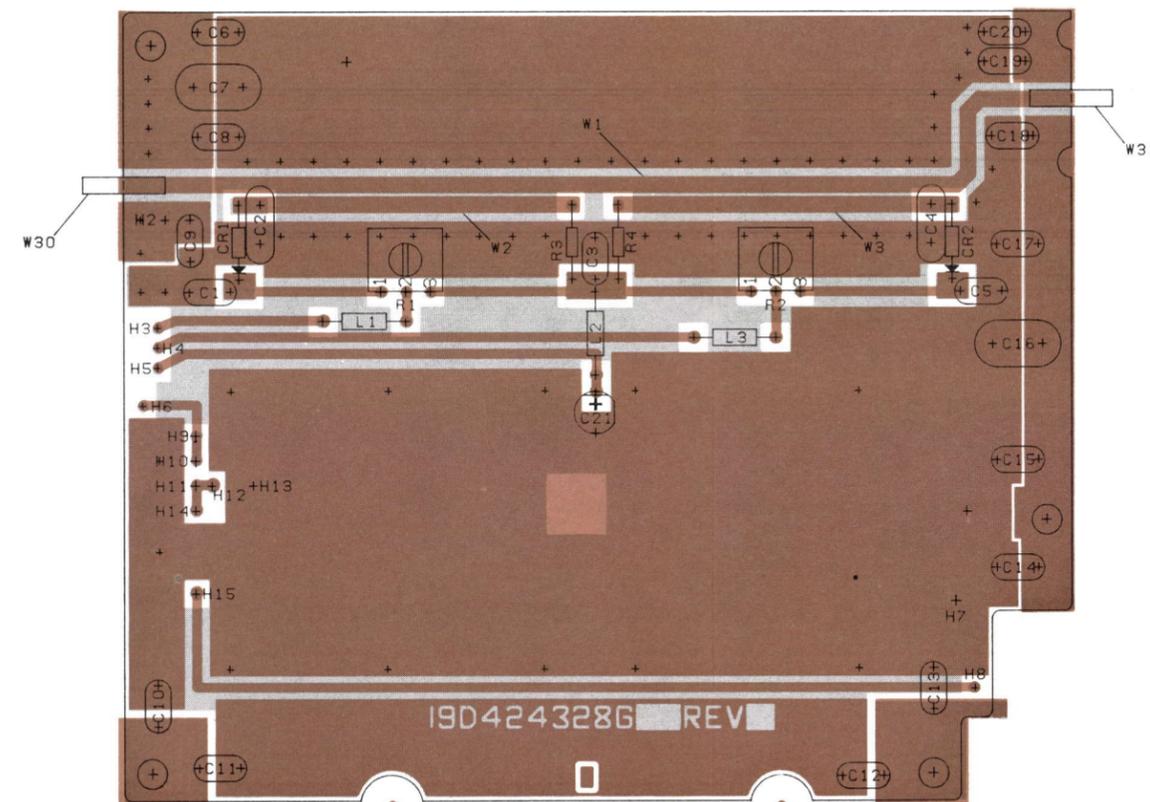


(19C327842, Rev. 1)
(19B227265, Sh. 1, Rev. 1)
(19B227265, Sh. 2, Rev. 0)

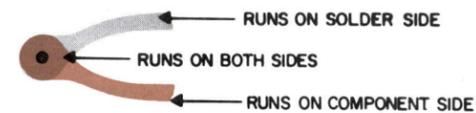
BOTTOM VIEW



(19D430129, Rev. 0)



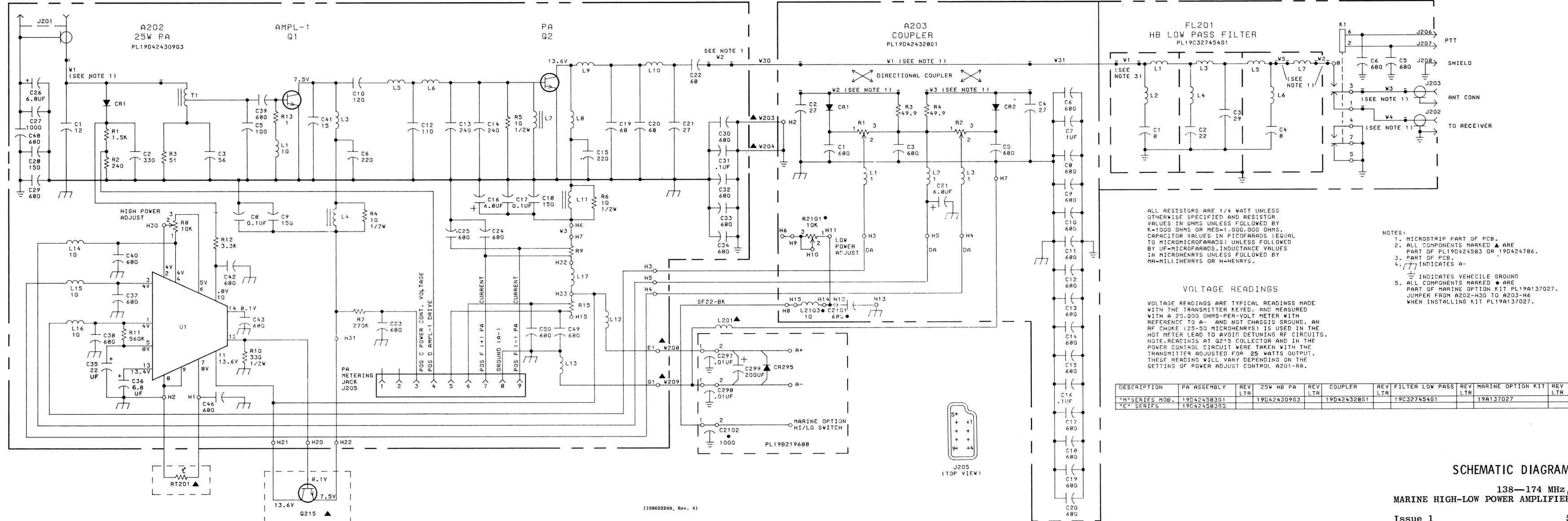
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(19B227638, Sh. 1, Rev. 0)
(19B227638, Sh. 2, Rev. 0)



OUTLINE DIAGRAMS

138—174 MHz POWER AMPLIFIER ASSEMBLIES
(MARINE HIGH-LOW POWER OPTION)

ANY CHANGE TO THIS DRAWING
MAY AFFECT 19R622290



SCHEMATIC DIAGRAM

138-174 MHz,
MARINE HIGH-LOW POWER AMPLIFIER

(19R622288, Rev. 4)

SYMBOL	GE PART NO.	DESCRIPTION
A201	19D424309G1	10 Watt Driver. (Used with 19D424583G2, G4, G6 & G8).
A202	19D424309G3	25 Watt Driver/PA. (Used with 19D424583G1, G3, G5, G7).
A203	19D424328G1	Coupler. (Used with 19D424583G1, G5).
A204	19D424872G1	40 Watt Power Amplifier. (Used with 19D424583G2, G6).
A205	19D424872G2	65 Watt Power Amplifier. (Used with 19D424583G3, G7).
A206	19D424266G1	110 Watt Power Amplifier. (Used with 19D424583G4, G8).
FL201		FILTERS COMPONENT BOARD 19C327454G1
C1	19A11667998D	Metalized teflon: 8 pf .5 pf, 250 VDCV.
C2	19A116679922J	Metalized teflon: 22 pf 15%, 250 VDCV.
C3	19A116795929J	Metalized teflon: 29 pf 15%, 250 VDCV.
C4	19A11667998D	Metalized teflon: 8 pf .5 pf, 250 VDCV.
C5 and C6	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
J202 and J203	19A130924G1	Connector, receptacle: coaxial, jack type; sim to Cinch 14811613.
J206 and J207	19A134263P2	Contact, electrical: sim to Selectro 229-1071.
J208	4033513M	Contact, electrical: sim to Bead Chain L93-3.
K1	19B209558P1	RELAYS Hermetic sealed: 180 to 341 ohm coil res; 2 form C contacts, 8-0 to 16-3 VDC; sim to GE 88A17604Z.
L1	19A129569P1	INDUCTORS Coil.
L2	19A129570P1	Coil.
L3	19A129569P1	Coil.
L4	19A129575P1	Coil.
L5	19A129569P1	Coil.
L6	19A129570P1	Coil.
L7	19A136907P1	Coil.
W1 thru W5		CABLES (Part of printed board 19D424357P1).
L201 and L202	19A129562P1	INDUCTORS Coil.

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

SYMBOL	GE PART NO.	DESCRIPTION
Q215	19A116742P1	TRANSISTORS Silicon, NPN.
RT01	19A129379G1	Thermistor: 40K ohms ±20%, color code white; sim to Carborandum Type M080J1-5.
W203	19A136942P1	CABLES Strap.
W204	7878455P1	Terminal, lug.
W205	19B227912P1	Jumper.
W206	19B227931G3	Jumper.
W207	19B227931G1	Jumper.
W208	19B227074G1	Jumper.
W209	19B226725G1	Jumper.
W210	19B227934G1	Cable: approx 13 inches long.
W211	19A137008P2	Jumper.
C297 and C298	19A116708P1	CAPACITORS Ceramic, feed-thru: 0.01 pf ±10% -0%, 500 VDCV; sim to Erie 327050X5W103P.
C299	19A116680P10	Electrolytic: 200 pf ±50% -10%, 18 VDCV; sim to Mallory Type TX.
CR295	19A116783P1	DIODES AND RECTIFIERS Rectifier, silicon: 100 VDC blocking, 6 amps.
	19D41673207	MISCELLANEOUS Heat sink. ("M" SERIES).
	19D417105G7	Heat sink. ("E" SERIES).
	19A134016P1	Insulator, bushing. (Used with Q215).
	19A116029P3	Insulator, plate. (Used with Q215).
	19C321982P1	Insulator. (Located under A201, A202).
	19C321442P1	Insulator. (Located under A203-A206).
	NP280427	Nameplate. (25, 40, 65 Watt- Located on FL201).
	NP280428	Nameplate. (110 Watt- Located on FL201).
	19B201074P306	Tap screw, Phillips POZIDRIV®: No. 6-32 x 3/8. (Located between FL201 cover and A203-A206-Quantity 2).
	19B201074P305	Tap screw, Phillips POZIDRIV®: No. 6-32 x 3/8. (Located between FL201 cover and A203-A206-Quantity 2).
	N404913C6	Lockwasher, internal tooth: No. 6. (Located between FL201 cover and A203-A206).
	19B201074P320	Tap screw, Phillips POZIDRIV®: No. 6-32 x 1-1/4. (Secures FL201 cover).
	19A116080P107	INDUCTORS Polyester: 0.1 pf ±10%, 50 VDCV.
	N449010C6	Machine screw: No. 4-40 x 3/8. (Secures Q1 & Q2 on A201, A202; Q1 on A204, A205; Q1-Q2 on A206).
	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
	N8091300C6	Machine screw, Phillips head: No. 6-32 x 3/8. (Secures A201-A206 boards).
	19A134202P6	Tantalum: 22 pf ±20%, 15 VDCV.
	19A124202P15	Tantalum: 6.8 pf ±20%, 35 VDCV.
	19A129569P1	Coil.
	7141223P2	Hex nut: No. 4-40. (Used with Q215 mounting).
	19A129570P1	Coil.
	N809900C6	Machine screw, Phillips head: No. 4-40 x 3/8. (Used with Q215 mounting).
	19A129434P1	Washer, fiber. (Located on terminals of C297 & C298).
	19B219929P1	Support, heat sink.
	19B209209P306	Tap screw, Phillips POZIDRIV®: No. 6-32 x 3/8. (Secures support to heat sink-Quantity 3).
	19A129639P1	Cover, heat sink.
	19B201074P305	Tap screw, Phillips POZIDRIV®: No. 6-32 x 5/16. (Secures heat sink cover).

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

SYMBOL	GE PART NO.	DESCRIPTION
C18	7489162P7	CAPACITORS Silver mica: 12 pf 15%, 500 VDCV; sim to Electro Motive Type DM-15.
C2	7489162P39	Silver mica: 330 pf ±5%, 500 VDCV; sim to Electro Motive Type DM-15.
C3	7489162P21	Silver mica: 56 pf ±5%, 500 VDCV; sim to Electro Motive Type DM-15.
C5B	19A116679P100J	Silver mica: 100 pf ±5%, 250 VDCV.
C6	19A116679P220J	Silver mica: 220 pf ±5%, 250 VDCV.
C8	19A116655P8	Ceramic disc: 150 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C9	19A116655P8	Ceramic disc: 150 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C10B	7489162P29	Silver mica: 120 pf ±5%, 500 VDCV; sim to Electro Motive Type DM-15.
C12	19A116679P110J	Silver mica: 110 pf ±5%, 250 VDCV.
C13B	19A116952P240	Silver mica: 240 pf ±5%, 250 VDCV; sim to Underwood Type JHF.
C14B	19A116952P240	Silver mica: 240 pf ±5%, 250 VDCV; sim to Underwood Type JHF.
C15	19A116679P220J	Silver mica: 220 pf ±5%, 250 VDCV.
C16	19A134202P15	Tantalum: 6.8 pf ±20%, 35 VDCV.
C17	19A116080P107	Polyester: 0.1 pf ±10%, 50 VDCV.
C18	19A116655P8	Ceramic disc: 150 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C19	19A116679P68J	Silver mica: 68 pf ±5%, 250 VDCV.
C20B	19A116679P68J	Silver mica: 68 pf ±5%, 250 VDCV.
C21B	19A116679P27J	Silver mica: 27 pf ±5%, 250 VDCV.
C22B	19A116679P68J	Silver mica: 68 pf ±5%, 250 VDCV.
C23 thru C25	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C26	19A134202P15	Tantalum: 6.8 pf ±20%, 35 VDCV.
C27	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCV; sim to RMC Type JF Discap.
C28	19A116655P8	Ceramic disc: 150 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C29 and C30	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C31	19A116080P107	Polyester: 0.1 pf ±10%, 50 VDCV.
C32 thru C34	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C35	19A134202P6	Tantalum: 22 pf ±20%, 15 VDCV.
C36	19A124202P15	Tantalum: 6.8 pf ±20%, 35 VDCV.
C37 thru C40	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C41	7489162P8	Silver mica: 15 pf ±5%, 500 VDCV; sim to Electro Motive Type DM-15.
C42 and C43	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C46	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C48 thru C50	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

SYMBOL	GE PART NO.	DESCRIPTION
CR1	19A115250P1	DIODES AND RECTIFIERS Silicon, fast recovery, 225 mA, 50 PIV.
E1	19A134263P1	CONTACT, ELECTRICAL: sim to Selectro 229-1082-00-0-590.
G1	19A134263P1	CONTACT, ELECTRICAL: sim to Selectro 229-1082-00-0-590.
J201	19A130924G1	JACKS AND RECEPTACLES Connector, receptacle: coaxial, jack type; sim to Cinch 14811613.
J205	19B219374G1	CONNECTOR: 9 contacts.
L1	19B209420P125	INDUCTORS Coil, RF: 10.0 pH ±10%, 3.10 ohms DC res max; sim to Jeffers 4446-4.
L3A	19A136530P1	Coil.
L4	19A129773G1	Coil.
L5B	19A136532P1	Coil.
L6	19A129773P1	Coil.
L7	19A129773G1	Coil.
L8B	19A136531P1	Coil.
L9B	19A12975P1	Coil.
L10B	19A136533P1	Coil.
L11	19A129773G1	Coil.
L12 and L13	19A129689P1	Coil.
L14 thru L18	19B209420P125	Coil, RF: 10.0 pH ±10%, 3.10 ohms DC res max; sim to Jeffers 4446-4.
L17	19A129575P1	Coil.
Q1	19A134340P1	TRANSISTORS Silicon, NPN.
Q2B	19A134340P2	Silicon, NPN.
R1 and R2	3R152P152J	RESISTORS Composition: 1.5K ohms 15%, 1/4 w.
R3	3R152P241J	Composition: 240 ohms 15%, 1/4 w.
R4	3R152P10J	Composition: 51 ohms 15%, 1/4 w.
R4 thru R8	3R77P100J	Composition: 10 ohms 15%, 1/2 w.
R8A	3R152P274J	Composition: 270K ohms 15%, 1/4 w.
R9	19A116559P106	Variable, cermet: 10K ohms ±20%, 0.5 w; sim to CTS Series 360.
R10	19C320212P2	Shunt resistor.
R11	3R77P331J	Composition: 330 ohms 15%, 1/2 w.
R12	3R152P964J	Composition: 560K ohms 15%, 1/4 w.
R13	3R152P332J	Composition: 3.3K ohms 15%, 1/4 w.
R15	19A116216P1R0K	Deposited carbon: 1.0 ohms ±10%, 1/4 w; sim to Amperex Type B803104 Style CR25.
T1	19C320212P2	Shunt resistor.
U1	19A129564G1	TRANSFORMERS Coil.
W1 and W2	19D429709G1	INTEGRATED CIRCUITS IC, Power Control.
W3	19B227912P1	CABLES (Part of printed board 19D424308P1).
W3	19A136950P1	MISCELLANEOUS Jumper. Strap. (Solders to W2).

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

SYMBOL	GE PART NO.	DESCRIPTION
CR1	19A115250P1	DIODES AND RECTIFIERS Silicon, fast recovery, 225 mA, 50 PIV.
E1	19A134263P1	CONTACT, ELECTRICAL: sim to Selectro 229-1082-00-0-590.
G1	19A134263P1	CONTACT, ELECTRICAL: sim to Selectro 229-1082-00-0-590.
J201	19A130924G1	JACKS AND RECEPTACLES Connector, receptacle: coaxial, jack type; sim to Cinch 14811613.
J205	19B219374G1	CONNECTOR: 9 contacts.
L1	19B209420P125	INDUCTORS Coil, RF: 10.0 pH ±10%, 3.10 ohms DC res max; sim to Jeffers 4446-4.
L3A	19A136530P1	Coil.
L4	19A129773G1	Coil.
L5B	19A136532P1	Coil.
L6	19A129773P1	Coil.
L7	19A129773G1	Coil.
L8B	19A136531P1	Coil.
L9B	19A12975P1	Coil.
L10B	19A136533P1	Coil.
L11	19A129773G1	Coil.
L12 and L13	19A129689P1	Coil.
L14 thru L18	19B209420P125	Coil, RF: 10.0 pH ±10%, 3.10 ohms DC res max; sim to Jeffers 4446-4.
L17	19A129575P1	Coil.
Q1	19A134340P1	TRANSISTORS Silicon, NPN.
Q2B	19A134340P2	Silicon, NPN.
R1 and R2	3R152P152J	RESISTORS Composition: 1.5K ohms 15%, 1/4 w.
R3	3R152P241J	Composition: 240 ohms 15%, 1/4 w.
R4	3R152P10J	Composition: 51 ohms 15%, 1/4 w.
R4 thru R8	3R77P100J	Composition: 10 ohms 15%, 1/2 w.
R8A	3R152P274J	Composition: 270K ohms 15%, 1/4 w.
R9	19A116559P106	Variable, cermet: 10K ohms ±20%, 0.5 w; sim to CTS Series 360.
R10	19C320212P2	Shunt resistor.
R11	3R77P331J	Composition: 330 ohms 15%, 1/2 w.
R12	3R152P964J	Composition: 560K ohms 15%, 1/4 w.
R13	3R152P332J	Composition: 3.3K ohms 15%, 1/4 w.
R15	19A116216P1R0K	Deposited carbon: 1.0 ohms ±10%, 1/4 w; sim to Amperex Type B803104 Style CR25.
T1	19C320212P2	Shunt resistor.
U1	19A129564G1	TRANSFORMERS Coil.
W1 and W2	19D429709G1	INTEGRATED CIRCUITS IC, Power Control.
W3	19B227912P1	CABLES (Part of printed board 19D424308P1).
W3	19A136950P1	MISCELLANEOUS Jumper. Strap. (Solders to W2).

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

SYMBOL	GE PART NO.	DESCRIPTION
C1	19A116655P18	CAPACITORS Ceramic disc: 680 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C2	7489162P13	Silver mica: 27 pf ±5%, 500 VDCV; sim to Electro Motive Type DM-15.
C3	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C4	7489162P13	Silver mica: 27 pf ±5%, 500 VDCV; sim to Electro Motive Type DM-15.
C5 and C6	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C7	19A116080P107	Polyester: 0.1 pf ±10%, 50 VDCV.
C8 thru C15	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C16	19A116080P107	Polyester: 0.1 pf ±10%, 50 VDCV.
C17 thru C20	19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C21	19A134202P15	Tantalum: 6.8 pf ±20%, 35 VDCV.
CR1 and CR2	19A116052P2	DIODES AND RECTIFIERS Hot carrier: Forward drop .410 volts max.
L1 thru L3	19B209420P113	INDUCTORS Coil, RF: 1.00 pH ±10%, 0.74 ohms DC res max; sim to Jeffers 4426-8K.
R1 and R2	19A116559P101	RESISTORS Variable, cermet: 1K ohms ±20%, 0.5 w; sim to CTS Series 360.
R3 and R4	19C314256P24999	Metal film: 49.9 ohms ±1%, 1/4 w.
W1 thru W3	19A136950P1	CABLES (Part of printed board 19D424327P1).

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

SYMBOL	GE PART NO.	DESCRIPTION
C2101	19A116655P18	CAPACITORS Ceramic disc: 680 pf ±10%, 1000 VDCV; sim to RMC Type JF Discap.
C2102	19B209503P3	Ceramic, feed-thru: 1000 pf ±10% -10%, 100 VDCV; sim to Erie Style 3429-002.
L2103	19B209420P125	INDUCTORS Coil, RF: 10.0 pH ±10%, 3.10 ohms DC res max; sim to Jeffers 4446-4.
R2101	19A116559P106	RESISTORS Variable, cermet: 10K ohms ±20%, 0.5 w; sim to CTS Series 360.
N403P16C6		MISCELLANEOUS Lockwasher, external tooth: No. 8.
NP270753P1		MISCELLANEOUS Nameplate. (VOLUME-POWER ON-HI LOW-SQUELCH).
19A116807P1		CLIP, spring tension. (Secures CR1701).
19B201074P204		Tap screw, Phillips POZIDRIV®: No. 4-40 x 1/4. (Secures front end of S1701).
N117P9004C6		Tap screw, Phillips: No. 4-40 x 1/4. (Secures rear end of S1701).

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES